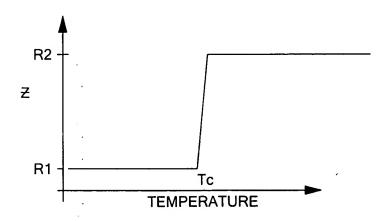
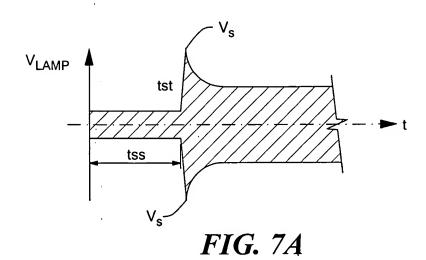


FIG. 5

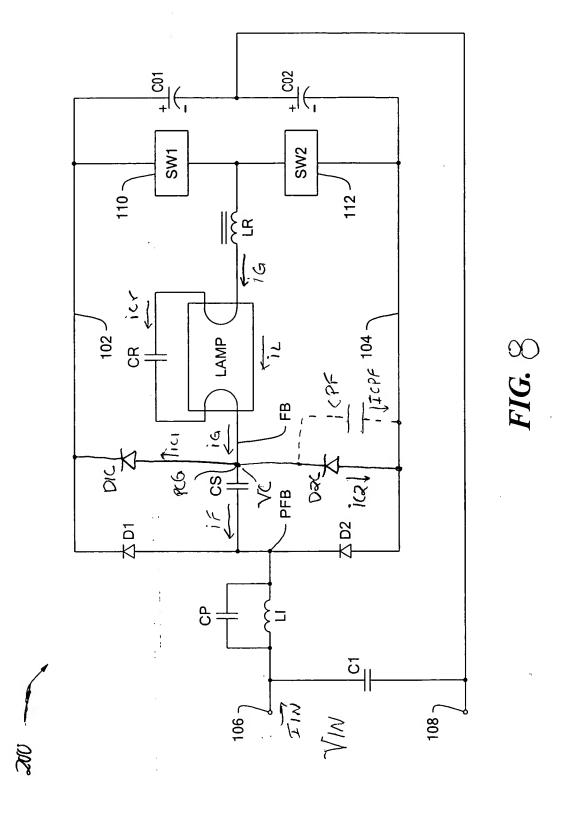


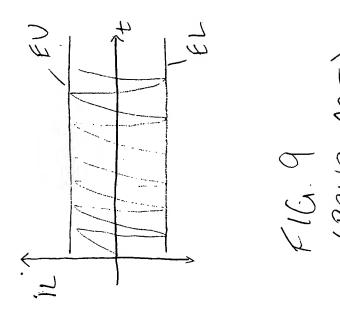
*FIG.* 6

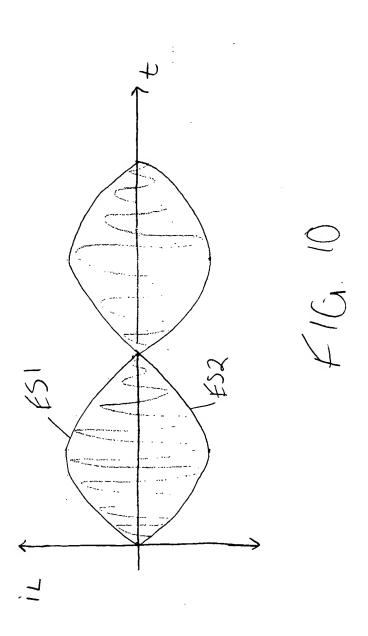


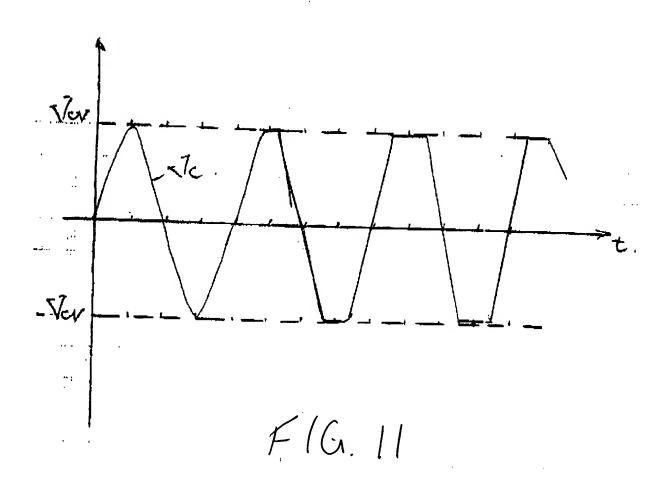
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FIG. 7B

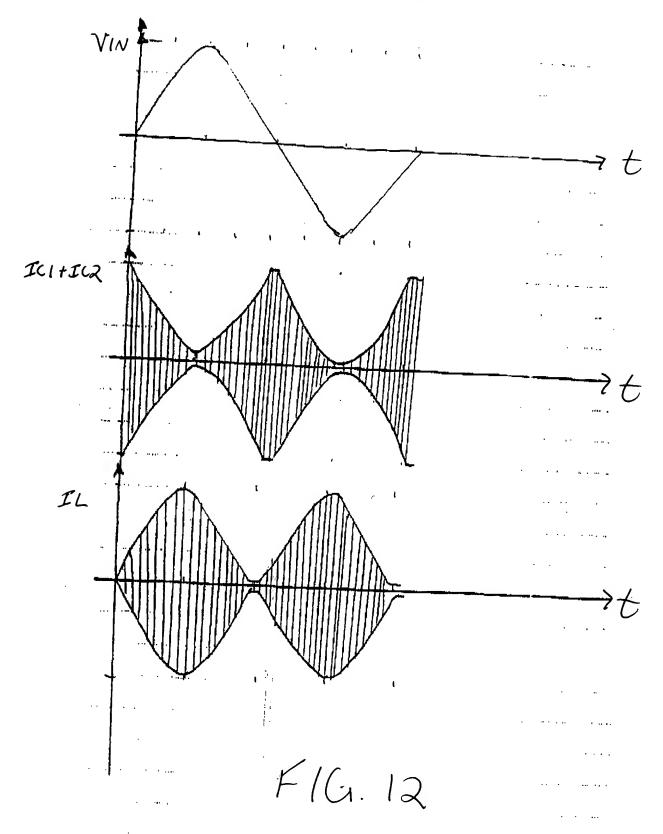






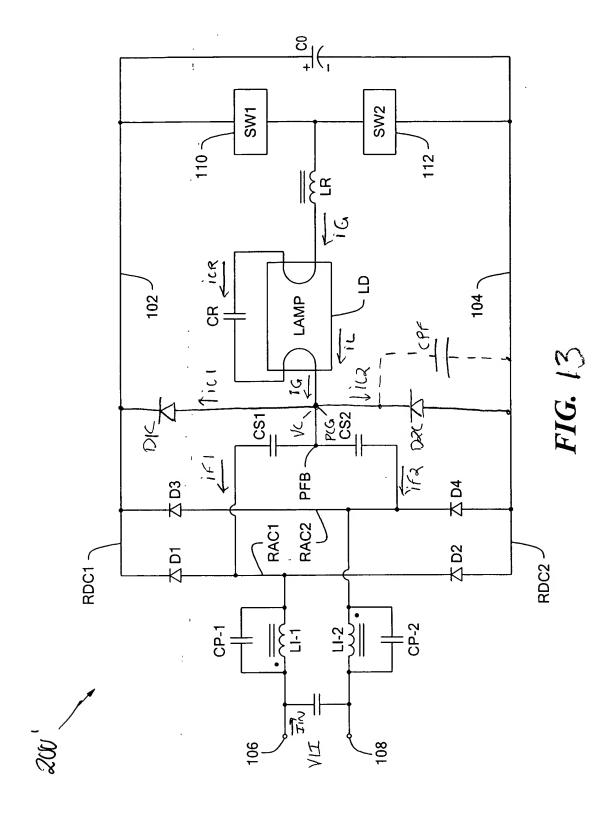


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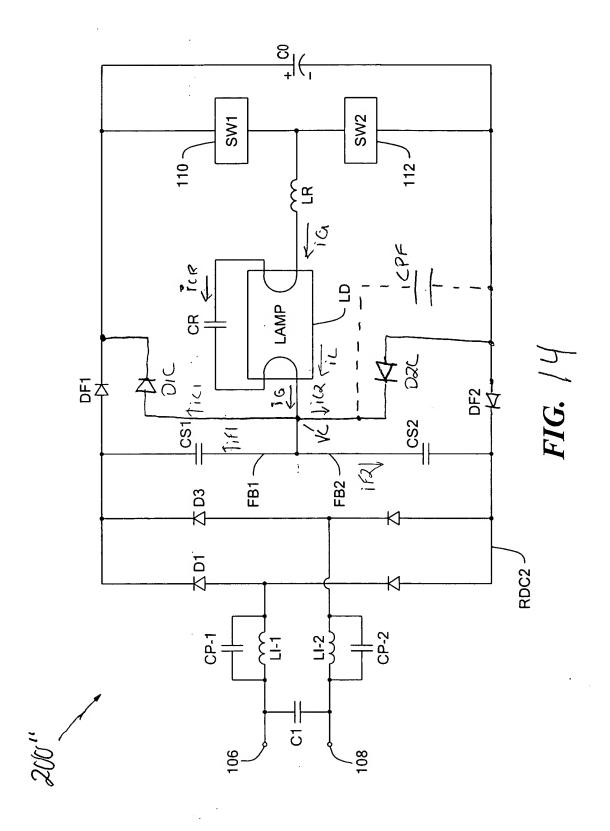


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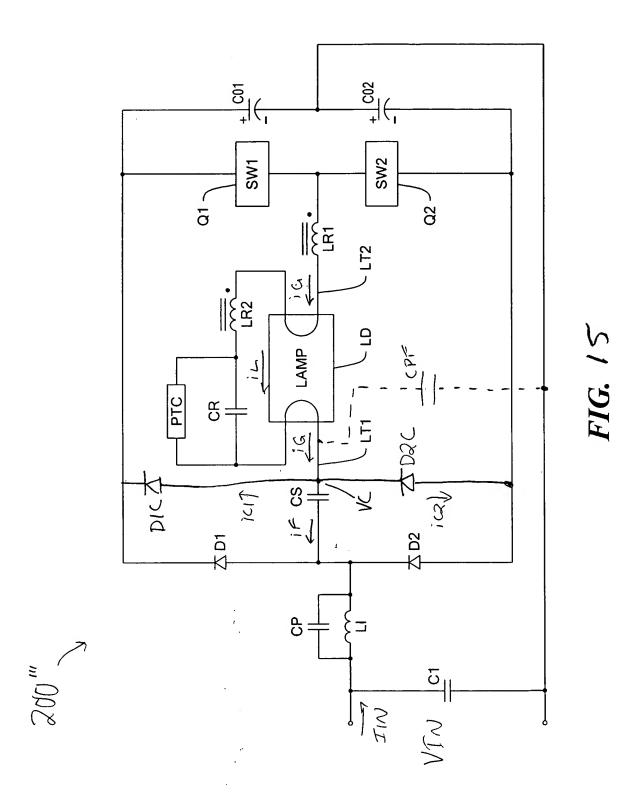
12/19



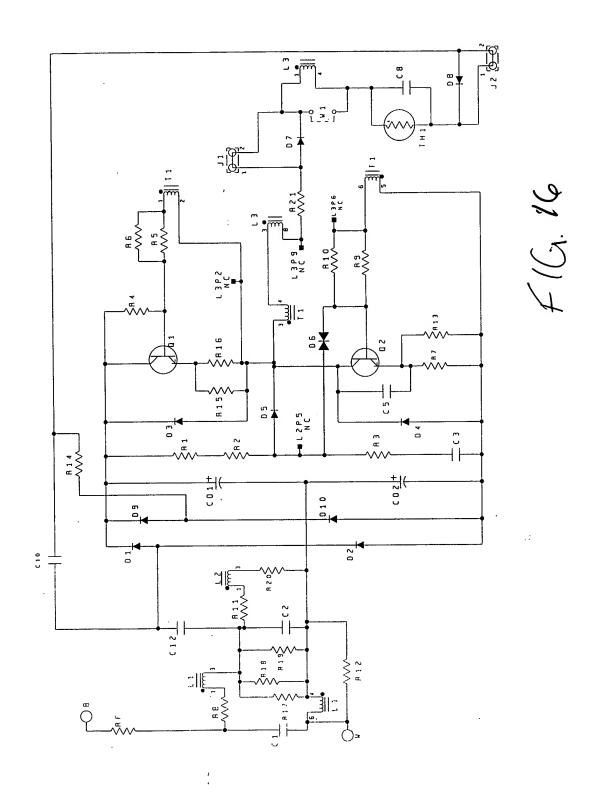
13/19



14/19

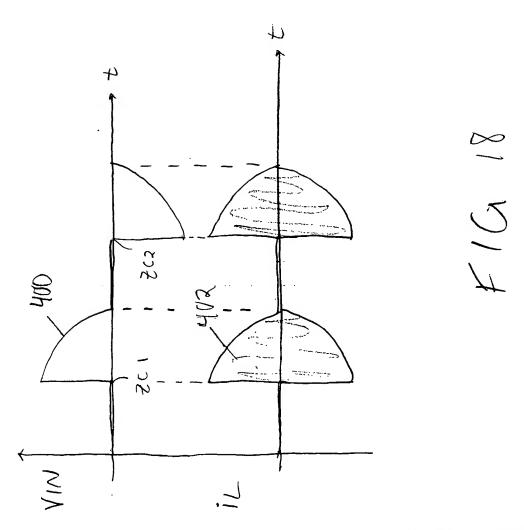


15/19

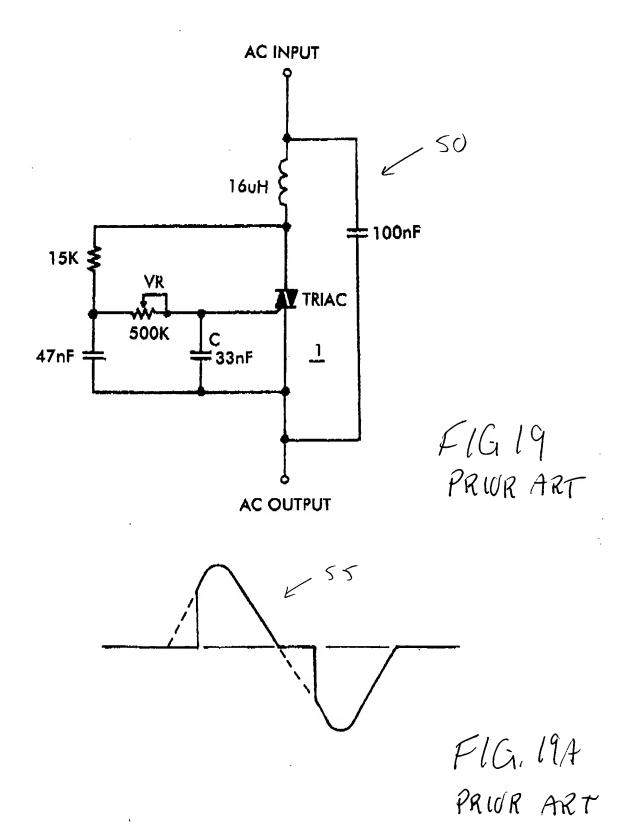


F161.17

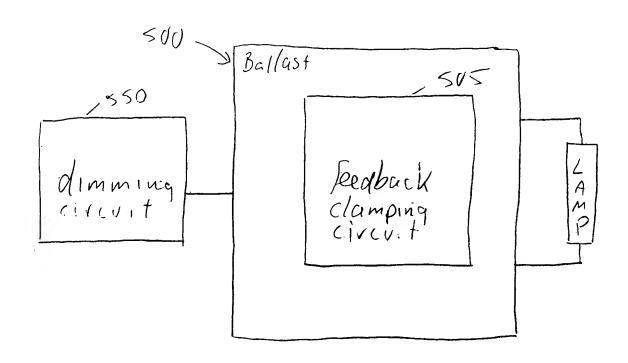
REF. DESIGN.	DESCRIPTION
L3	Inductor Assy, 1.69mH (+/-3%), AL=100
	130T/10T, 3x33AWG Litz, 7pin, CS-L3
L2 L1	Inductor Assy, 1.90mH, AL=65
	171T, 29AWGH, 5pin, CS-L2
	Inductor Assy, 1.90mH, AL=65
	171T, 29AWGH, 5pin, CS-L2
T1	Torroid Transformer, CSI
	H40-T(9x4x5) (1-1-5)T
C3	Capacitor, Ceramic, SMD,
	0.1uF, 50Vdc, 10%, 1206 Pkg.
C1	Capacitor, Metallized Polyester, 5mm
	0.01uF, 400Vdc, 10%
C2	Capacitor, Metallized Polyester, 5mm
	Epoxy-Dipped, 33nF, 250Vdc, 10%
. C12	Capacitor, Plypropylene, 5mm
	Epoxy-Dipepd, 2.7nF, 400Vdc, 10%
C5	Capacitor, Ceramic, Radial
	100pF, 1000Vdc, 5 mm
C8 .	Capacitor, Polypropylene. 5mm
	Epoxy-Dipped, 2.2nF, 1500V,10%
C10	Capcitor, Polypropylene, 5mm
	Epoxy-Dipped, 4.7nF, 400Vdc, 10%
CO1,CO2	Capacitor, Electrolytic, (10x20)mm
331,332	33uF, 200Vdc, 105C, 5mm
D5	Diode, Axial, Glass-Passivated
	Fast, 1000V, 1N4007GP
D1-D4, D9-D10	Diode, Axial, Glass-Passivated
	Ultra-Fast, 1000V, UF4007GP
D6	Diac, Axial, 32V Db 3
RF	Fuse, Axial
<u>``</u>	3A/250V
R7, R15	Resistor, SMD, 1206 Pkg,
	0 Ohm
R8, R11, R12,	Resistor, SMD,1206 Fkg,
R14, R20, R21	0 Ohm
R6, R10, R13, R16	Resistor, SMD, 1206 Pkg,
NOT USED	Tresistor, SIVID, 1200 Pkg,
R3	Resistor, SMD,1206 Pkg,
	33 Ohm, 5%, 1/4W
R5, R9,	Resistor, SMD,1206 Pkg,
	20 Ohm, 1%, 1/4W
R1,R2	Resistor, SMD,1206 Fkg,
1,11,1%	150 kOhm, 5%, 1/4W
R4	
T. T	Resistor, SMD, 1206 Pkg,
R17-R19	300 kOhm, 5%, 1/4W
NOT USED	Resistor, SMD, 1206 Pkg,
Q1,Q2	Transistas De TO 200
	Transistor Power, TO-220
J1, J1	ST13005
· · · · · · · · · · · · · · · · · · ·	Terminal, Radial,
TH1	2 pin, CSI
NOT USED	Thermistor, PTC
NOT BOLD	



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